# **Dual Schmitt-Trigger Inverter**

The NL27WZ14 is a high performance dual inverter with Schmitt–Trigger inputs operating from a 1.65 to 5.5 V supply.

Pin configuration and function are the same as the NL27WZ04, but the inputs have hysteresis and, with its Schmitt trigger function, the NL27WZ14 can be used as a line receiver which will receive slow input signals. The NL27WZ14 is capable of transforming slowly changing input signals into sharply defined, jitter–free output signals. In addition, it has a greater noise margin than conventional inverters. The NL27WZ14 has hysteresis between the positive–going and the negative–going input thresholds (typically 1.0 V) which is determined internally by transistor ratios and is essentially insensitive to temperature and supply voltage variations.

#### **Features**

- Designed for 1.65 V to 5.5 V V<sub>CC</sub> Operation
- Over Voltage Tolerant Inputs and Outputs
- LVTTL Compatible Interface Capability with 5.0 V TTL Logic with  $V_{CC} = 3.0 \text{ V}$
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- Current Drive Capability is 24 mA at the Outputs
- Chip Complexity: FET = 72
- Pb-Free Packages are Available

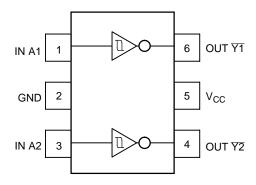


Figure 1. Pinout (Top View)

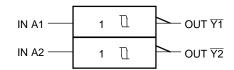


Figure 2. Logic Symbol



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SC-88/SOT-363/SC70-6 DF SUFFIX CASE 419B





TSOP-6/SOT-23-6/SC59-6 DT SUFFIX CASE 318G



MA = Device Marking M = Date Code

A = Assembly Location W, WW = Work Week • Pb-Free Package

(Note: Microdot may be in either location)

#### PIN ASSIGNMENT

| Pin | Function        |
|-----|-----------------|
| 1   | IN A1           |
| 2   | GND             |
| 3   | IN A2           |
| 4   | OUT Y2          |
| 5   | V <sub>CC</sub> |
| 6   | OUT Y1          |

# **FUNCTION TABLE**

| A Input | ₹ Output |
|---------|----------|
| L       | Н        |
| Н       | L        |

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

#### **MAXIMUM RATINGS**

| Symbol           | Characteristics   | Value                    | Unit |
|------------------|---|--------------------------|------|
| V <sub>CC</sub>  | DC Supply Voltage   | -0.5  to  +7.0           | V    |
| VI               | DC Input Voltage  | $-0.5 \le V_1 \le +7.0$  | V    |
| Vo               | DC Output Voltage Output in Z or LOW State (Note 1)   | $-0.5 \le V_{O} \le 7.0$ | V    |
| I <sub>IK</sub>  | DC Input Diode Current V <sub>I</sub> < GND   | -50                      | mA   |
| I <sub>OK</sub>  | DC Output Diode Current V <sub>O</sub> < GND  | -50                      | mA   |
| I <sub>O</sub>   | DC Output Sink Current  | ± 50                     | mA   |
| I <sub>CC</sub>  | DC Supply Current per Supply Pin  | ± 100                    | mA   |
| I <sub>GND</sub> | DC Ground Current per Ground Pin  | ± 100                    | mA   |
| T <sub>STG</sub> | Storage Temperature Range   | -65 to +150              | °C   |
| P <sub>D</sub>   | Power Dissipation in Still Air SC-88, TSOP-6  | 200                      | mW   |
| $\theta_{JA}$    | Thermal Resistance SC-88, TSOP-6  | 333                      | °C/W |
| TL               | Lead Temperature, 1 mm from case for 10 s   | 260                      | °C   |
| $T_J$            | Junction Temperature under Bias   | + 150                    | °C   |
| V <sub>ESD</sub> | ESD Withstand Voltage  Human Body Model (Note 2)  Machine Model (Note 3)  Charged Device Model (Note 4) | > 2000<br>> 200<br>N/A   | V    |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

- I<sub>O</sub> absolute maximum rating must be observed.
   Tested to EIA/JESD22-A114-A
   Tested to EIA/JESD22-A115-A

- 4. Tested to JESD22-C101-A

# **RECOMMENDED OPERATING CONDITIONS**

| Symbol          | Parameter                          |  | Min         | Max                              | Unit |
|-----------------|------------------------------------|--|-------------|----------------------------------|------|
| V <sub>CC</sub> | Supply Voltage                     | Operating<br>Data Retention Only   | 2.3<br>1.5  | 5.5<br>5.5                       | V    |
| VI              | Input Voltage                      |  | 0           | 5.5                              | V    |
| Vo              | Output Voltage                     | (High or LOW State)  | 0           | 5.5                              | V    |
| T <sub>A</sub>  | Operating Free–Air Temperature     |  | <b>- 55</b> | + 125                            | °C   |
| Δt/ΔV           | Input Transition Rise or Fall Rate | $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$<br>$V_{CC} = 3.0 \text{ V} \pm 0.3 \text{ V}$<br>$V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$ | 0<br>0<br>0 | No Limit<br>No Limit<br>No Limit | ns/V |

# **ORDERING INFORMATION**

| Device Order Number | Package Type<br>(Name/SOT#/Common Name) | Tape and Reel Size <sup>†</sup>  |
|---------------------|---|----------------------------------|
| NL27WZ14DFT2        | SC-88/SOT-363/SC70-6                    | 178 mm, 3000 Units / Tape & Reel |
| NL27WZ14DFT2G       | SC-88/SOT-363/SC70-6<br>(Pb-Free)       | 178 mm, 3000 Units / Tape & Reel |
| NL27WZ14DTT1        | TSOP-6/SOT-23-6/SC59-6                  | 178 mm, 3000 Units / Tape & Reel |
| NL27WZ14DTT1G       | TSOP-6/SOT-23-6/SC59-6<br>(Pb-Free)     | 178 mm, 3000 Units / Tape & Reel |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### DC ELECTRICAL CHARACTERISTICS

|                  |  |  | V <sub>CC</sub>  | $T_A$  | = 25°C   |  | $-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le 85^{\circ}\text{C}$ |  | $-55^{\circ}C \le T_{A} \le 125^{\circ}C$                        |  |      |
|------------------|--|--|--|--|--|--|--|--|--|--|------|
| Symbol           | Parameter  | Condition  | (V)  | Min  | Тур  | Max  | Min  | Max                                      | Min  | Max                                      | Unit |
| V <sub>T</sub> + | Positive Input<br>Threshold Voltage  |  | 2.3<br>2.7<br>3.0<br>4.5                               | 1.0<br>1.2<br>1.3<br>1.9   | 1.5<br>1.7<br>1.9<br>2.7                                   | 1.8<br>2.0<br>2.2<br>3.1                         | 1.0<br>1.2<br>1.3<br>1.9   | 1.8<br>2.0<br>2.2<br>3.1                 | 1.0<br>1.2<br>1.3<br>1.9   | 1.8<br>2.0<br>2.2<br>3.1                 | >    |
| V <sub>T</sub> - | Negative Input<br>Threshold Voltage  |  | 5.5<br>2.3<br>2.7<br>3.0<br>4.5<br>5.5                 | 2.2<br>0.4<br>0.5<br>0.6<br>1.0<br>1.2                           | 3.3<br>0.75<br>0.87<br>1.0<br>1.5<br>1.9                   | 3.6<br>1.15<br>1.4<br>1.5<br>2.0<br>2.3          | 2.2<br>0.4<br>0.5<br>0.6<br>1.0<br>1.2                               | 3.6<br>1.15<br>1.4<br>1.5<br>2.0<br>2.3  | 2.2<br>0.4<br>0.5<br>0.6<br>1.0<br>1.2                           | 3.6<br>1.15<br>1.4<br>1.5<br>2.0<br>2.3  | V    |
| V <sub>H</sub>   | Input Hysteresis<br>Voltage  |  | 2.3<br>2.7<br>3.0<br>4.5<br>5.5                        | 0.25<br>0.3<br>0.4<br>0.6<br>0.7                                 | 0.75<br>0.83<br>0.93<br>1.2<br>1.4                         | 1.1<br>1.15<br>1.2<br>1.5<br>1.7                 | 0.25<br>0.3<br>0.4<br>0.6<br>0.7                                     | 1.1<br>1.15<br>1.2<br>1.5<br>1.7         | 0.25<br>0.3<br>0.4<br>0.6<br>0.7                                 | 1.1<br>1.15<br>1.2<br>1.5<br>1.7         | V    |
| V <sub>OH</sub>  | High-Level<br>Output Voltage<br>V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> | $\begin{split} I_{OH} &= -100 \; \mu A \\ I_{OH} &= -3 \; mA \\ I_{OH} &= -8 \; mA \\ I_{OH} &= -12 \; mA \\ I_{OH} &= -16 \; mA \\ I_{OH} &= -24 \; mA \\ I_{OH} &= -32 \; mA \\ \end{split}$                                       | 1.65 to 5.5<br>1.65<br>2.3<br>2.7<br>3.0<br>3.0<br>4.5 | V <sub>CC</sub> - 0.1<br>1.29<br>1.9<br>2.2<br>2.4<br>2.3<br>3.8 | V <sub>CC</sub><br>1.52<br>2.1<br>2.4<br>2.7<br>2.5<br>4.0 |  | V <sub>CC</sub> - 0.1<br>1.29<br>1.9<br>2.2<br>2.4<br>2.3<br>3.8     |  | V <sub>CC</sub> - 0.1<br>1.29<br>1.8<br>2.1<br>2.3<br>2.2<br>3.7 |  | V    |
| V <sub>OL</sub>  | Low-Level<br>Output Voltage<br>V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>  | $\begin{split} I_{OL} &= 100 \; \mu\text{A} \\ I_{OL} &= 4 \; \text{mA} \\ I_{OL} &= 8 \; \text{mA} \\ I_{OL} &= 12 \; \text{mA} \\ I_{OL} &= 16 \; \text{mA} \\ I_{OL} &= 24 \; \text{mA} \\ I_{OL} &= 32 \; \text{mA} \end{split}$ | 1.65 to 5.5<br>1.65<br>2.3<br>2.7<br>3.0<br>3.0<br>4.5 |  | 0.08<br>0.2<br>0.22<br>0.28<br>0.38<br>0.42                | 0.1<br>0.24<br>0.3<br>0.4<br>0.4<br>0.55<br>0.55 |  | 0.1<br>0.24<br>0.3<br>0.4<br>0.4<br>0.55 |  | 0.1<br>0.24<br>0.4<br>0.5<br>0.5<br>0.55 | V    |
| I <sub>IN</sub>  | Input Leakage<br>Current   | $V_{IN} = V_{CC}$ or GND   | 0 to 5.5   |  |  | ±0.1   |  | ± 1.0                                    |  | ± 1.0                                    | μΑ   |
| I <sub>OFF</sub> | Power Off–Output<br>Leakage Current  | V <sub>OUT</sub> = 5.5 V   | 0  |  |  | 1  |  | 10                                       |  | 10                                       | μΑ   |
| I <sub>CC</sub>  | Quiescent Supply<br>Current  | $V_{IN} = V_{CC}$ or GND   | 5.5  |  |  | 1  |  | 10                                       |  | 10                                       | μΑ   |

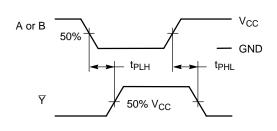
# AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$ )

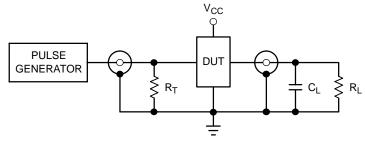
|                  |   |   |                     | T,         | T <sub>A</sub> = 25°C |            | T <sub>A</sub> = 25°C |            | T <sub>A</sub> = 25°C |            | -40°C ≤ | <b>T</b> <sub>A</sub> ≤ 85°C | -55°C ≤ 1 | T <sub>A</sub> ≤ 125°C |  |
|------------------|---|---|---------------------|------------|-----------------------|------------|-----------------------|------------|-----------------------|------------|---------|------------------------------|-----------|------------------------|--|
| Symbol           | Parameter                                 | Condition   | V <sub>CC</sub> (V) | Min        | Тур                   | Max        | Min                   | Max        | Min                   | Max        | Unit    |                              |           |                        |  |
| t <sub>PLH</sub> | Propagation                               | $R_L = 1 \text{ M}\Omega$ , $C_L = 15 \text{ pF}$   | $2.5 \pm 0.2$       | 1.8        | 4.3                   | 7.4        | 1.8                   | 8.1        | 1.8                   | 9.1        | ns      |                              |           |                        |  |
| t <sub>PHL</sub> | Delay<br>Input A to Y<br>(Figure 3 and 4) | $R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$<br>$R_L = 500 \Omega, C_L = 50 \text{ pF}$ |                     | 1.5<br>1.8 | 3.3<br>4.0            | 5.0<br>6.0 | 1.5<br>1.8            | 5.5<br>6.6 | 1.5<br>1.8            | 6.5<br>7.6 |         |                              |           |                        |  |
|                  |   | $R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$<br>$R_L = 500 \Omega, C_L = 50 \text{ pF}$ |                     | 1.0<br>1.2 | 2.7<br>3.2            | 4.1<br>4.9 | 1.0<br>1.2            | 4.5<br>5.4 | 1.0<br>1.2            | 5.5<br>6.4 |         |                              |           |                        |  |

# **CAPACITIVE CHARACTERISTICS**

| Symbol          | Parameter                              | Condition  | Typical    | Unit |
|-----------------|--|--|------------|------|
| C <sub>IN</sub> | Input Capacitance                      | $V_{CC}$ =5.5 V, $V_{I}$ = 0 V or $V_{CC}$   | 2.5        | pF   |
| C <sub>PD</sub> | Power Dissipation Capacitance (Note 5) | 10 MHz, $V_{CC} = 3.3 \text{ V}$ , $V_I = 0 \text{ V or } V_{CC}$<br>10 MHz, $V_{CC} = 5.0 \text{ V}$ , $V_I = 0 \text{ V or } V_{CC}$ | 11<br>12.5 | pF   |

<sup>5.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no–load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.





 $R_T = C_L$  or equivalent (includes jog and probe capacitance)

 $R_T = Z_{OUT}$  of pulse generator (typically 50  $\Omega$ )

Figure 3. Switching Waveforms

Figure 4. Test Circuit

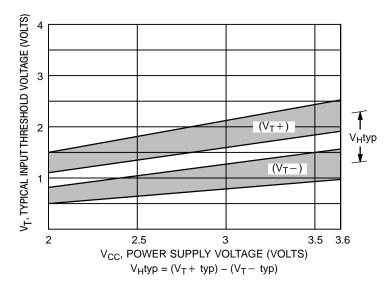
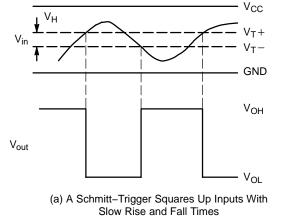
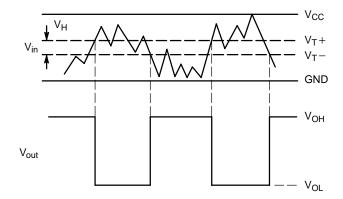


Figure 5. Typical Input Threshold,  $V_{\mathsf{T}^+}, V_{\mathsf{T}^-}$  versus Power Supply Voltage



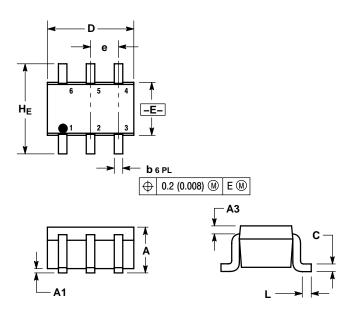


(b) A Schmitt-Trigger Offers Maximum Noise Immunity

Figure 6. Typical Schmitt-Trigger Applications

# **PACKAGE DIMENSIONS**

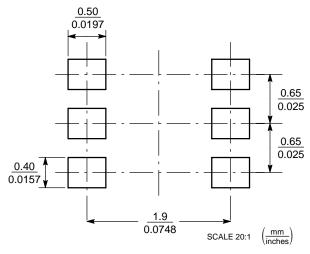
#### SC70-6/SC-88/SOT-363 **DF SUFFIX** CASE 419B-02 ISSUE V



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. 419B-01 OBSOLETE, NEW STANDARD 419B-02.

|     | MIL  | LIMETE  | ERS  |       | INCHES   | 3     |
|-----|------|---------|------|-------|----------|-------|
| DIM | MIN  | NOM     | MAX  | MIN   | NOM      | MAX   |
| Α   | 0.80 | 0.95    | 1.10 | 0.031 | 0.037    | 0.043 |
| A1  | 0.00 | 0.05    | 0.10 | 0.000 | 0.002    | 0.004 |
| A3  |      | 0.20 RE | F    |       | 0.008 RI | EF    |
| b   | 0.10 | 0.21    | 0.30 | 0.004 | 0.008    | 0.012 |
| С   | 0.10 | 0.14    | 0.25 | 0.004 | 0.005    | 0.010 |
| D   | 1.80 | 2.00    | 2.20 | 0.070 | 0.078    | 0.086 |
| Е   | 1.15 | 1.25    | 1.35 | 0.045 | 0.049    | 0.053 |
| е   |      | 0.65 BS | С    | 0     | .026 BS  | С     |
| L   | 0.10 | 0.20    | 0.30 | 0.004 | 0.008    | 0.012 |
| HF  | 2.00 | 2.10    | 2.20 | 0.078 | 0.082    | 0.086 |

#### **SOLDERING FOOTPRINT\***

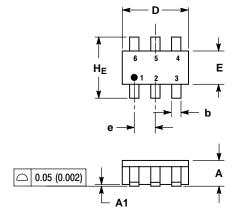


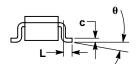
\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

#### SOT23-6/TSOP-6/SC59-6 **DT SUFFIX**

CASE 318G-02 ISSUE P



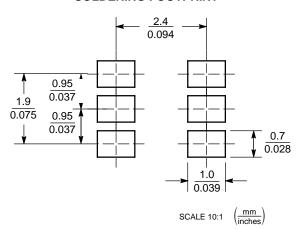


#### NOTES:

- DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: MILLIMETER.
  MAXIMUM LEAD THICKNESS INCLUDES LEAD
  FINISH THICKNESS. MINIMUM LEAD
- THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE

|     | М     | ILLIMETE | RS    |        | INCHES |        |
|-----|-------|----------|-------|--------|--------|--------|
| DIM | MIN   | NOM      | MAX   | MIN    | NOM    | MAX    |
| Α   | 0.90  | 1.00     | 1.10  | 0.0354 | 0.0394 | 0.0433 |
| A1  | 0.013 | 0.06     | 0.100 | 0.0005 | 0.0022 | 0.0040 |
| b   | 0.25  | 0.38     | 0.50  | 0.0098 | 0.0148 | 0.0197 |
| С   | 0.10  | 0.18     | 0.26  | 0.0040 | 0.0071 | 0.0102 |
| D   | 2.90  | 3.00     | 3.10  | 0.1142 | 0.1181 | 0.1220 |
| E   | 1.30  | 1.50     | 1.70  | 0.0512 | 0.0591 | 0.0669 |
| е   | 0.85  | 0.95     | 1.05  | 0.0335 | 0.0374 | 0.0413 |
| L   | 0.20  | 0.40     | 0.60  | 0.0079 | 0.0157 | 0.0236 |
| HE  | 2.50  | 2.75     | 3.00  | 0.0985 | 0.1083 | 0.1181 |
| θ   | 0°    | _        | 10°   | 0°     | _      | 10°    |

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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